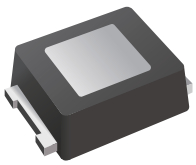
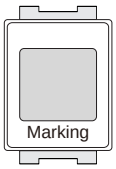
Description





RHP065AS Thyristor solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.
The RHP065AS device is usedto enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, and TIA-968 (formerly known as FCC Part 68).

Features

Compared to surge suppression using other technologies, The RHP065AS device offers absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). The RHP065AS device:

- Top-side Cooling(TSC) Packaging technology
- Compact and Slim Packaging Solutions
- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipati in typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigue
- Have low capacitance, making them ideal for high-speed transmission equipment
- Meets MSL level 1, per J-STD-020
- Lead free in comply with EU RoHS 2011/65/EU directives

Ordering Information

Part Number	Marking	Shipping	Reel
RHP065AS	P065	15000PCS Tape&Reel	13 inchs

Absolute Maximum Ratings (T_A=25°C)

Parameter	Symbol	Value	Unit
Operating Junction Temperature	T_J	-55 to +150	°C
Storage Temperature Range	T_S	-55 to +150	°C
Junction to Ambient on printed circuit	$R_{\theta JA}$	65	°C/W
Non-repetitive Peak Impulse Current 10/1000 μs	I_{PPSM}	45	A
Non-repetitive peak impulse Voltage 10/700 μs	V_{PPSM}	2000	V

Electrical Characteristics

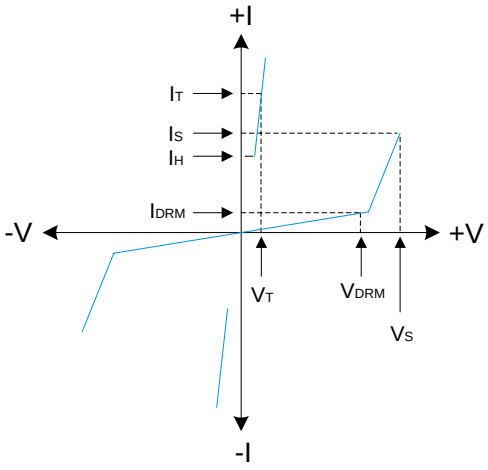
Part Number	V_{DRM} (V)	V_S (V)	V_T (V)	I_{DRM} (μA)	I_S (mA)	I_T (A)	I_H (mA)	C_O (pF)
RHP065AS	6	13	3	0.5	800	2.2	50	45

Notes:

- All measurements are made at an ambient temperature of 25˚C. I_{PP} applies to -40˚C through +85˚C temperature range.
- Off-state capacitance(C_O) is measured at 1 MHz with a 2V bias and is typical value.

Electrical Parameters

Parameter	Definition
V_{DRM}	**Peak Off-state Voltage –** maximum voltage that can be applied while maintaining off state
V_S	**Switching Voltage –** maximum voltage prior to switching to on state
V_T	**On-state Voltage –** maximum voltage measured at rated on-state current
I_{DRM}	**Leakage Current –** maximum peak off-state current measured at V_{DRM}
I_S	**Switching Current –** maximum current required to switch to on state
I_T	**On-state Current –** maximum rated continuous on-state current
I_H	**Holding Current –** typical current required to maintain on state
C_O	**Off-state Capacitance –** typical capacitance measured in off state
I_{PP}	**Peak Pulse Current –** maximum rated peak impulse current
I_{TSM}	**Peak One-cycle Surge Current –** maximum rated one-cycle AC current
di/dt	**Rate of Rise of Current –** maximum rated value of the acceptable rate of rise in current over time



Characteristics Curves

Fig.1 tr × td Pulse Wave-form

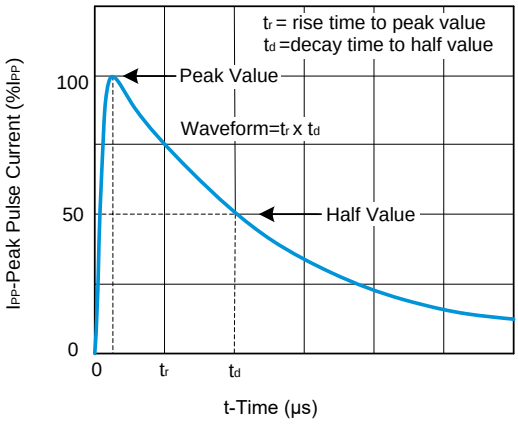


Fig.2 Normalized Vs Change versus Junction Temperature

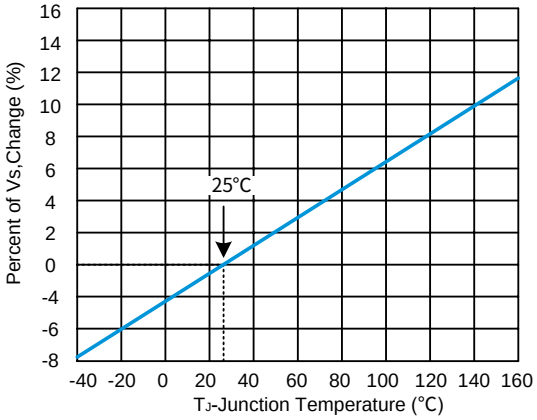
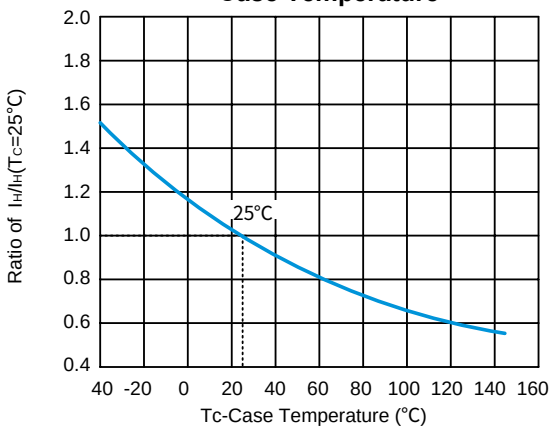


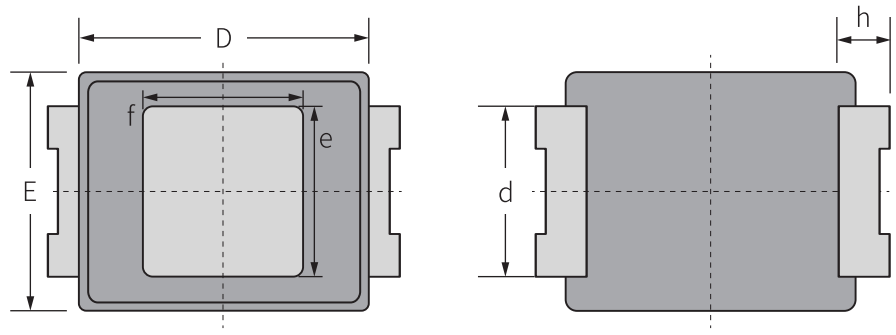
Fig.3 Normalized DC Holding Current versus Case Temperature

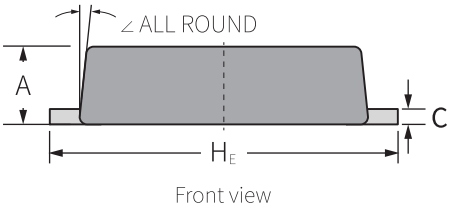


Package Outline

SMHS

Unit：mm



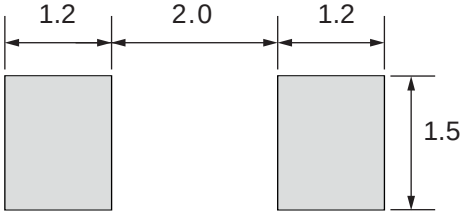


UNIT		A	C	D	E	H_E	d	e	f	h	∠
mm	max	0.99	0.25	2.90	2.10	3.50	1.30	1.30	1.25	0.70	6°
	min	0.83	0.15	2.50	1.70	2.90	1.10	1.10	1.05	0.50	

Suggested Pad Layout

SMHS

Unit：mm

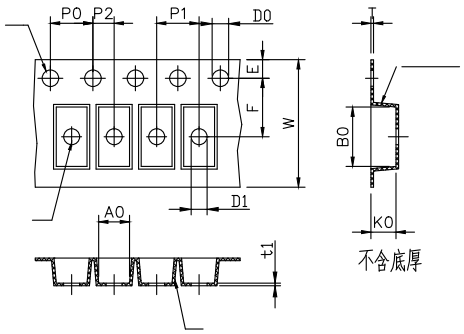


Note:

1. Controlling dimension:in millimeters.
2. General tolerance:±0.05mm
3. The pad layout is for reference purpose only.

Carrier Tape Dimensions

Unit：mm

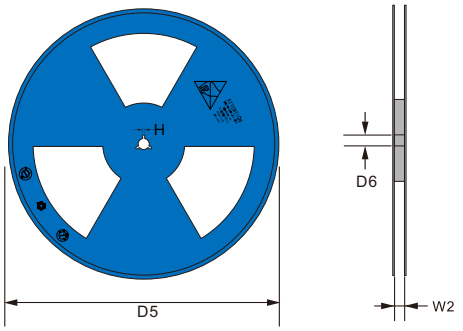


Symbol	Spec	Symbol	Spec
W	8.00±0.10	P2	2.00±0.10
E	1.75±0.10	t	0.22±0.02
F	3.50±0.10	t1	Min. 0.05
D0	1.55±0.10	A0	2.15±0.10
D1	1.05±0.10	B0	3.40±0.10
P0	4.00±0.10	K0	1.15±0.10
P1	4.00±0.10		

Reel Dimensions

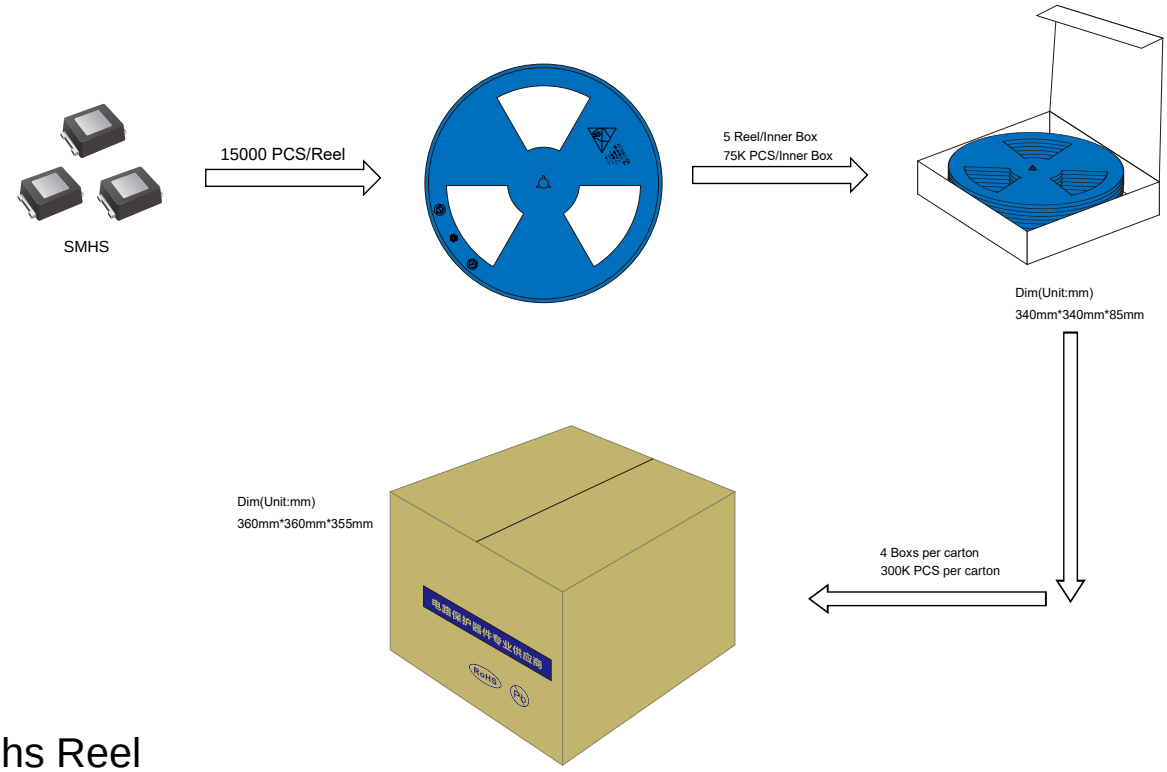
Unit：mm

13” Reel



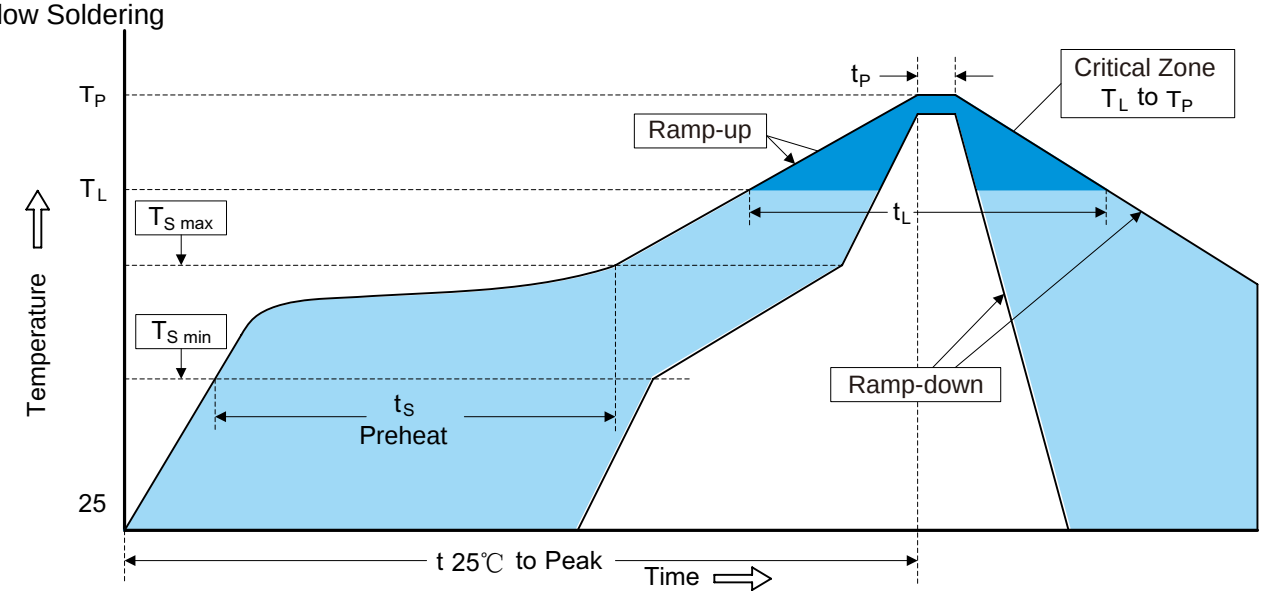
D5	Φ330.0±5.0
D6	Φ13.5±0.5
H	2.5±1.0
W2	8.0±2.0
Quantity: 15000PCS	

Packaging



Recommended Soldering Conditions

Reflow Soldering



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3℃/second max.
Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_S)	 150℃ 200℃ 60-180 seconds
$T_{S\ max}$ to T_L -Ramp-up Rate	 3℃/second max.
Time maintained above: -Temperature (T_L) -Time (t_L)	 217℃ 60-150 seconds
Peak Temperature (T_P)	260℃
Time within 5℃ of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down Rate	6℃/second max.
Time 25℃ to Peak Temperature	8 minutes max.